



2N40-CB

Power MOSFET

2A, 400V N-CHANNEL POWER MOSFET

DESCRIPTION

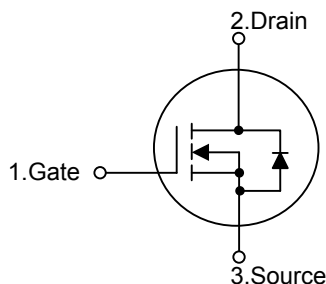
The UTC **2N40-CB** is a N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC **2N40-CB** is universally applied in electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.

FEATURES

- * $R_{DS(ON)} < 4.5\Omega @ V_{GS} = 10V, I_D = 1.0A$
- * High Switching Speed
- * 100% Avalanche Tested

SYMBOL

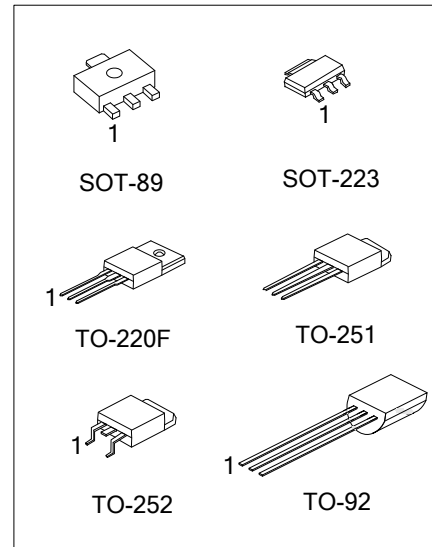


ORDERING INFORMATION

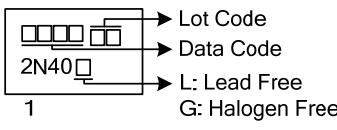
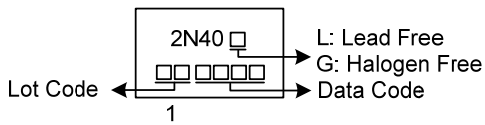
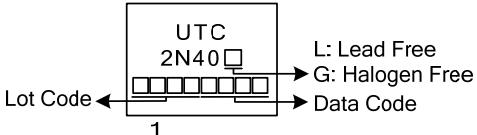
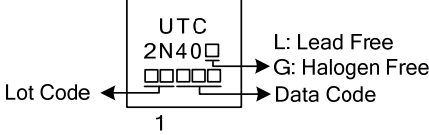
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2N40L-AA3-R	2N40G-AA3-R	SOT-223	G	D	S	Tape Reel
2N40L-AB3-R	2N40G-AB3-R	SOT-89	G	D	S	Tape Reel
2N40L-TF3-T	2N40G-TF3-T	TO-220F	G	D	S	Tube
2N40L-TM3-T	2N40G-TM3-T	TO-251	G	D	S	Tube
2N40L-TN3-R	2N40G-TN3-R	TO-252	G	D	S	Tape Reel
2N40L-T92-B	2N40G-T92-B	TO-92	G	D	S	Tape Box
2N40L-T92-K	2N40G-T92-K	TO-92	G	D	S	Bulk

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>2N40G-AA3-R</p> <p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Green Package</p>	<p>(1) R: Tape Reel, T: Tube, B: Tape Box, K: Bulk</p> <p>(2) AA3: SOT-223, TF3: TO-220F, TM3: TO-251</p> <p>TN3: TO-252, T92: TO-92</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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MARKING

SOT-89	SOT-223
 <p>Lot Code Data Code L: Lead Free G: Halogen Free</p>	 <p>Lot Code Data Code L: Lead Free G: Halogen Free</p>
TO-220F / TO-251 / TO-252	TO-92
 <p>Lot Code Data Code L: Lead Free G: Halogen Free</p>	 <p>Lot Code Data Code L: Lead Free G: Halogen Free</p>

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■ ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	400	V
Gate-Source Voltage		V_{GSS}	± 30	V
Drain Current ($T_C=25^\circ\text{C}$)	Continuous	I_D	2	A
	Pulsed (Note 2)	I_{DM}	8	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	34	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.9	V/ns
Power Dissipation ($T_C=25^\circ\text{C}$)	SOT-89	P_D	8.3	W
	TO-223		1	W
	TO-220F		23	W
	TO-251/TO-252		44	W
	TO-92		2	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 13 \text{ mH}$, $I_{AS} = 2.3\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 2.0\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER	PACKAGE	SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-89/TO-92	θ_{JA}	160	$^\circ\text{C}/\text{W}$
	SOT-223		150	$^\circ\text{C}/\text{W}$
	TO-220F		62.5	$^\circ\text{C}/\text{W}$
	TO-251/TO-252		110	$^\circ\text{C}/\text{W}$
Junction to Case	SOT-89	θ_{JC}	15	$^\circ\text{C}/\text{W}$
	SOT-223		125	$^\circ\text{C}/\text{W}$
	TO-220F		5.4	$^\circ\text{C}/\text{W}$
	TO-251/TO-252		2.8	$^\circ\text{C}/\text{W}$
	TO-92		62.5	$^\circ\text{C}/\text{W}$

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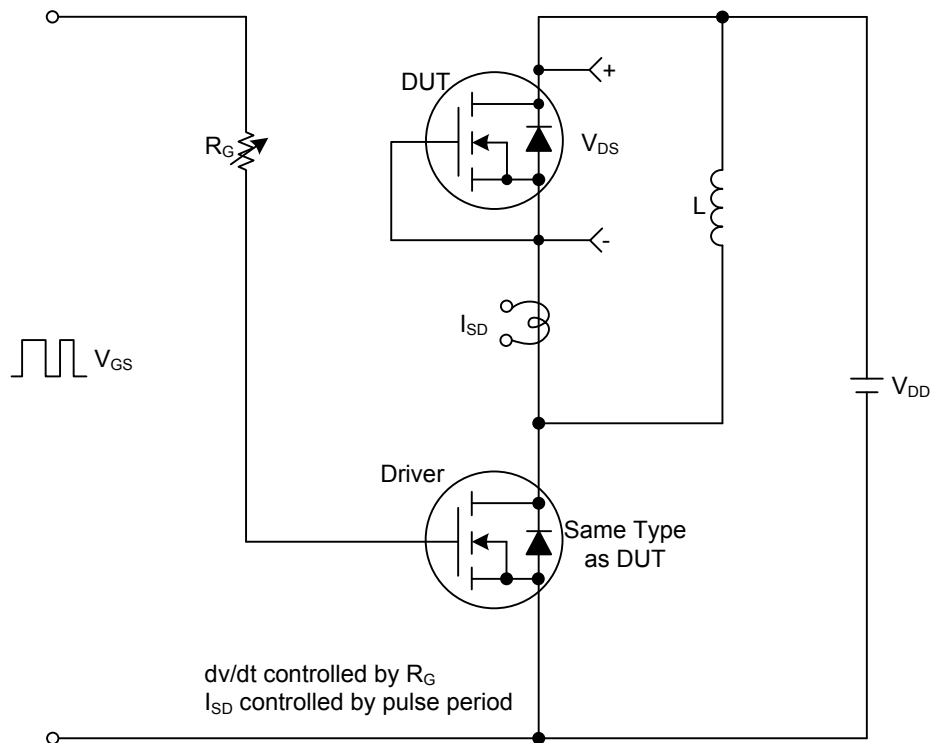
■ ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$	400			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=400\text{V}$, $V_{GS}=0\text{V}$			1	μA
Gate- Source Leakage Current	Forward	I_{GSS}			+100	nA
	Reverse				-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10\text{V}$, $I_D=1.0\text{A}$			4.5	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{GS}=0\text{V}$, $V_{DS}=25\text{V}$, $f=1.0\text{MHz}$		200		pF
Output Capacitance	C_{OSS}			35		pF
Reverse Transfer Capacitance	C_{RSS}			20		pF
SWITCHING PARAMETERS						
Total Gate Charge	Q_G	$V_{DS}=50\text{V}$, $V_{GS}=10\text{V}$, $I_D=1.3\text{A}$, $I_G=100\mu\text{A}$ (Note 1, 2)		14		nC
Gate to Source Charge	Q_{GS}			1.8		nC
Gate to Drain Charge	Q_{GD}			1.6		nC
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DD}=30\text{V}$, $V_{GS}=10\text{V}$, $I_D=0.5\text{A}$, $R_G=25\Omega$ (Note 1, 2)		37		ns
Rise Time	t_R			19		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			80		ns
Fall-Time	t_F			17		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Body-Diode Continuous Current	I_S				2	A
Maximum Body-Diode Pulsed Current	I_{SM}				8	A
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0\text{V}$, $I_S=2.0\text{A}$			1.4	V
Reverse Recovery Time	t_{rr}	$V_{GS}=0\text{V}$, $I_S=2.0\text{A}$		200		ns
Reverse Recovery Charge	Q_{rr}	$di_F/dt=100\text{A}/\mu\text{s}$ (Note 1)		0.5		μC

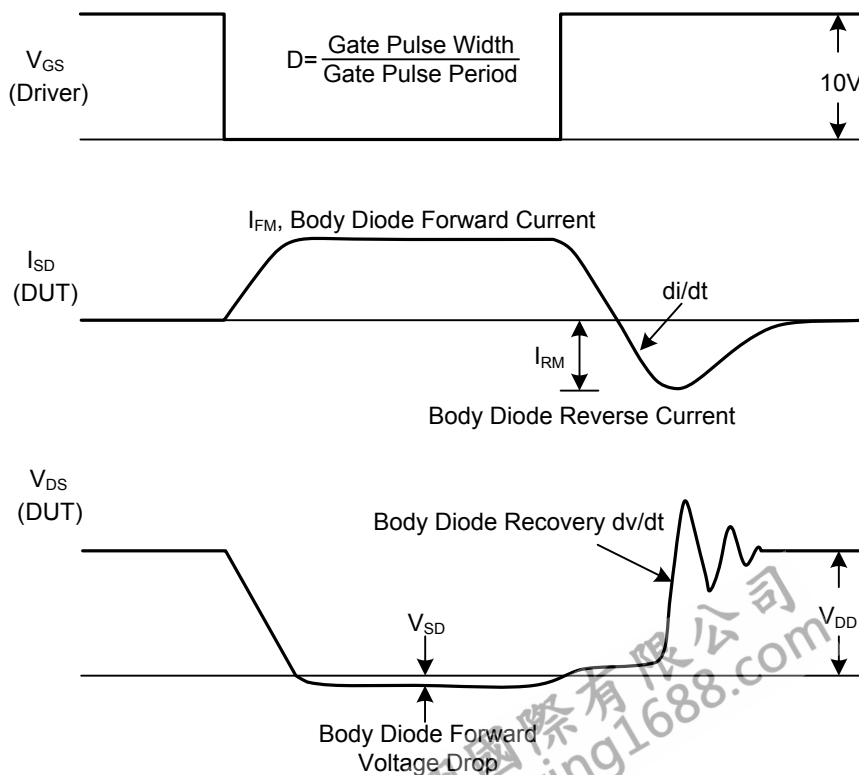
Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

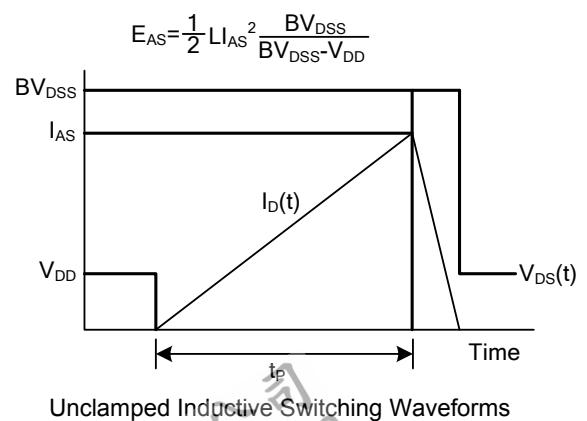
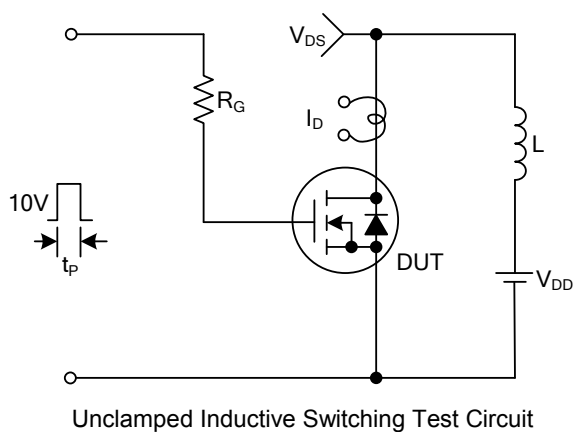
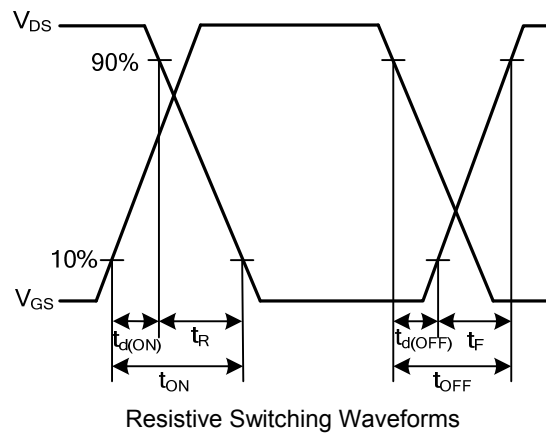
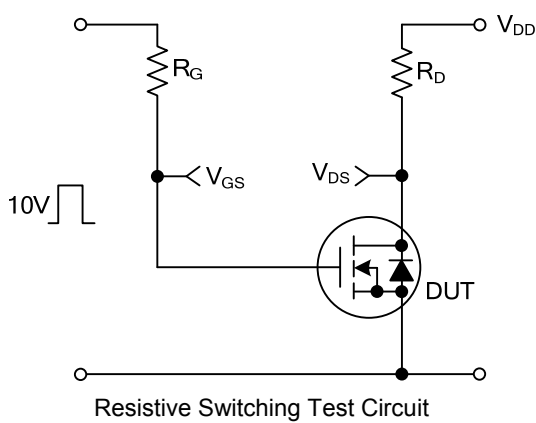
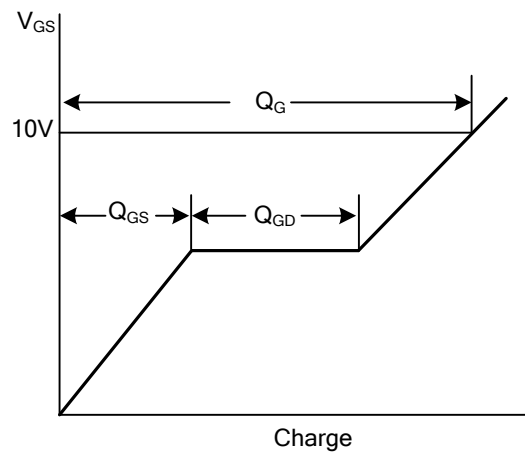
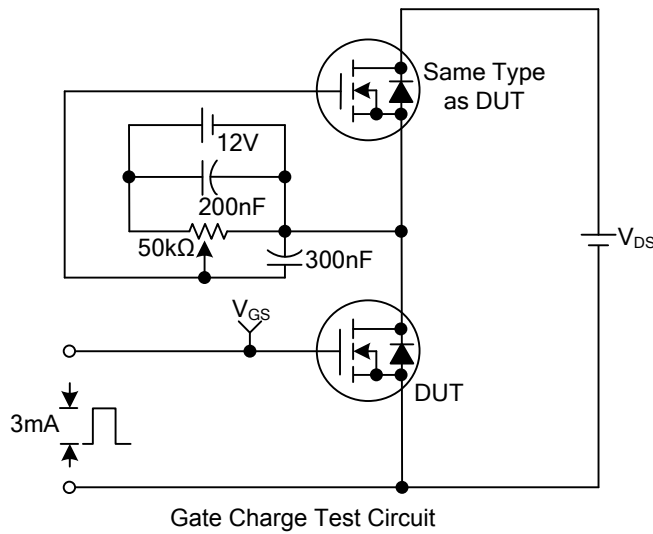
TEST CIRCUITS AND WAVEFORMS



Peak Diode Recovery dv/dt Test Circuit & Waveforms



TEST CIRCUITS AND WAVEFORMS (Cont.)



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